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1 Diagram

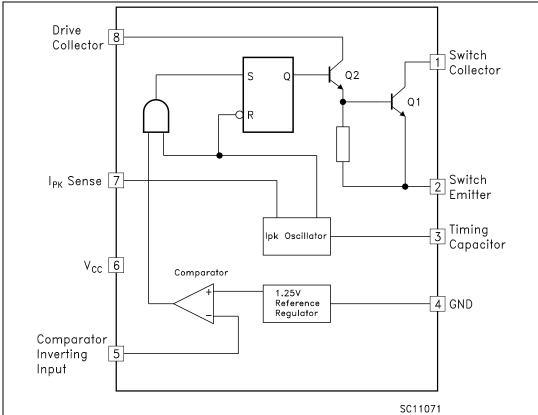


Figure 1. Block diagram

2 Pin configuration

Figure 2. Pin connections

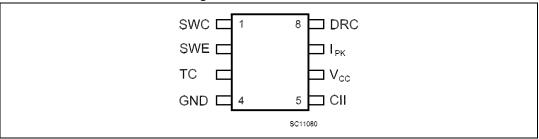


Table 2. Pin description

Pin n°	Symbol	Name and function
1	SWC	Switch collector
2	SWE	Switch emitter
3	TC	Timing capacitor
4	GND	Ground
5	CII	Comparator inverting input
6	V _{CC}	Voltage supply
7	I _{PK}	I _{PK} sense
8	DRC	Voltage driver collector

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Parameter		Unit	
V _{CC}	Power supply voltage		50	V	
V _{IR}	Comparator input voltage range		-0.3 to 40	V	
V _{SWC}	Switch collector voltage		40	V	
V _{SWE}	Switch emitter voltage (V _{SWC} = 4	0V)	40	V	
V _{CE}	Switch collector to emitter voltage	Э	40	V	
V_{DC}	Driver collector voltage	40	V		
I _{DC}	Driver collector current	100	mA		
I _{SW}	Switch current		1.5	Α	
0	Device dissination at T 0500	for DIP-8	1.25	10/	
P _{TOT}	Power dissipation at T _A = 25°C	for SO-8	0.625	W	
T _J	Operating junction temperature		150	°C	
T _{STG}	Storage temperature range		-40 to 150	°C	
	Operating ambient temperature range	carios	for AC and EC series	0 to 70	
T _{OP}		for AB series	-40 to 85	°C	
		for EB series	-40 to 125		

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 4. Thermal data

Symbol	Parameter	DIP-8	SO-8	Unit
R _{thJA}	Thermal resistance junction-ambient (1)	100	160	°C/W
R _{thJC}	Thermal resistance junction-case	42	20	°C/W

^{1.} This value depends from thermal design of PCB on which the device is mounted.

4 Electrical characteristics

Refer to the test circuits, $V_{CC} = 5 \text{ V}$, $T_A = T_{LOW}$ to T_{HIGH} , unless otherwise specified. (a)

Table 5. Oscillator

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
fosc	Frequency	$V_{PIN5} = 0V, C_T = 1 \text{ nF}, T_A = 25^{\circ}C$	24	33	42	kHz
I _{CHG}	Charge current	$V_{CC} = 5 \text{ to } 40V, T_A = 25^{\circ}C$	24	33	42	μΑ
I _{DISCHG}	Discharge current	$V_{CC} = 5 \text{ to } 40V, T_A = 25^{\circ}C$	140	200	260	μΑ
I _{DISCHG} /I _{CHG}	Discharge to charge current ratio	PIN 7 = V _{CC} , T _A = 25°C	5.2	6.2	7.5	μΑ
V _{IPK(sense)}	Current limit sense voltage	I _{CHG} = I _{DISCHG} , T _A = 25°C	250	300	350	mV

Table 6. Output switch

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{CE(sat)}	Saturation voltage, Darlington connection	I _{SW} = 1 A, PIN 1, 8 connected		1	1.3	V
V _{CE(sat)}	Saturation voltage	I_{SW} = 1 A, R_{PIN8} = 82 Ω to V_{CC} Forced β ~ 20		0.45	0.7	V
h _{FE}	DC current gain	I _{SW} = 1 A,V _{CE} = 5 V, T _A = 25°C	50	120		
I _{C(off)}	Collector off-state current	V _{CE} = 40 V		0.01	100	μΑ

Table 7. Comparator

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V	Throshold voltage	T _A = 25°C	1.225	1.25	1.275	V
VTH	V _{TH} Threshold voltage	$T_A = T_{LOW}$ to T_{HIGH}	1.21		1.29	v
Reg _{line}	Threshold voltage line regulation	V _{CC} = 3 to 40 V		1	10	mV
I _{IB}	Input bias current	V _{IN} = 0 V		-5	-400	nA

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a. T_{LOW} = 0 °C, T_{HIGH} = 70 °C (AC and EC series); T_{LOW} = -40 °C, T_{HIGH} = 85 °C (AB series); T_{LOW} = -40 °C, T_{HIGH} = 125 °C (EB series)

Table 8. Total device

Symbol	Parameter	Test condi	tions	Min.	Тур.	Max.	Unit
		V _{CC} = 5 to 40 V	for MC34063A		2.5	4	
Icc	Supply current	$C_T = 1 \text{ nF}$ $PIN 7 = V_{CC}$ $V_{PIN5} > V_{TH}$ PIN 2 = GND Remaining pins open	for MC34063E		1.5	4	mA
V	Start-up voltage ⁽¹⁾	T _A = 25°C	for MC34063A		2.1		٧
V _{START-UP}	Start-up Voltage	$C_{T} = 1 \mu F, PIN 5 = 0$	for MC34063E		1.5		٧

^{1.} Start-up voltage is the minimum power supply voltage at which the internal oscillator begins to work.

Note: Maximum package power dissipation limit must be observed.

If Darlington configuration is not used, care must be taken to avoid deep saturation of output switch. The resulting switch-off time may be adversely affected. In a Darlington configuration the following output driver condition is suggested:

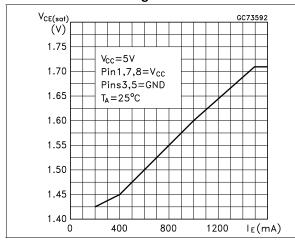
Forced β of output current switch = $I_{COUTPUT}/(I_{CDRIVER} - 1 \text{ mA}) \ge 10$



5 Typical performance characteristics

Figure 3. Emitter follower configuration output saturation voltage vs. emitter current

Figure 4. Output switch ON-OFF time vs. oscillator timing capacitor



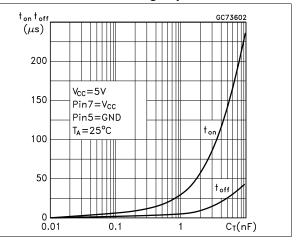
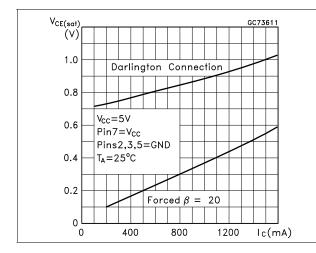


Figure 5. Common emitter configuration output switch saturation voltage vs. collector current

Figure 6. Darlington configuration collector emitter saturation voltage (V_{CEsat}) vs. temperature



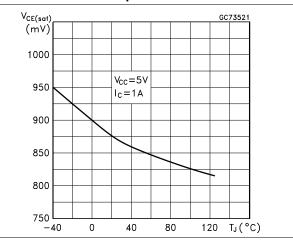
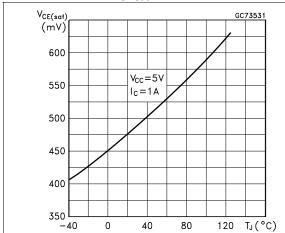


Figure 7. Power collector emitter saturation voltage (V_{CEsat}) vs. temperature

Figure 8. Current limit sense voltage (V_{IPK}) vs. temperature



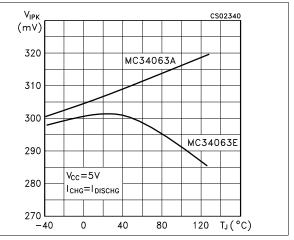
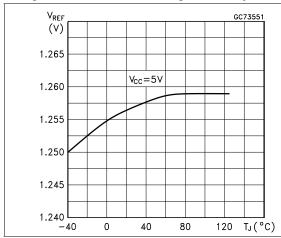


Figure 9. Reference voltage vs. temperature

Figure 10. Bias current vs. temperature



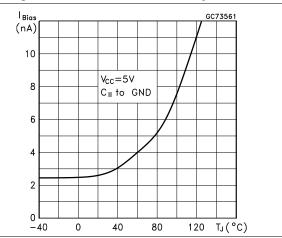
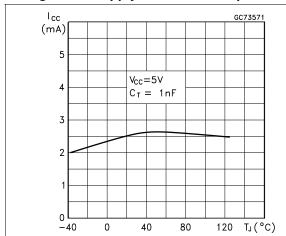
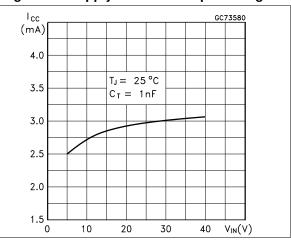


Figure 11. Supply current vs. temperature

Figure 12. Supply current vs. input voltage





6 Typical application circuit

170μH DRC SWC 180Ω SWE 2 I_{PK} D_1 ▼ BYV10-40 TC V_{CC} 0.22Ω GND 4 V_{IN}O CII O V OUT 28V/175mA MC34063A/E C₂ <u>⊑</u> 100μF C₃ R₁ 2.2ΚΩ 47ΚΩ ⊑ C₁ 330 μF SC11093

Figure 13. Step-up converter

Figure 14. Printed evaluation board

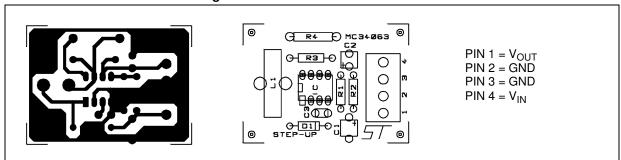


Table 9. Test condition (V_{OUT} = 28 V)

, 001			
Test	Conditions	Value (Typ.)	Unit
Line Regulation	$V_{IN} = 8 \text{ to } 16 \text{ V}, I_{O} = 175 \text{ mA}$	30	mV
Load Regulation	V _{IN} = 12 V, I _O = 75 to 175 mA	10	mV
Output Ripple	V _{IN} = 12 V, I _O = 175 mA	300	mV
Efficiency	V _{IN} = 12 V, I _O = 175 mA	89	%

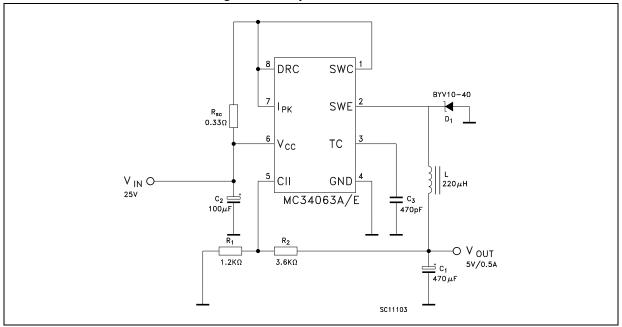


Figure 15. Step-down converter

Figure 16. Printed evaluation board

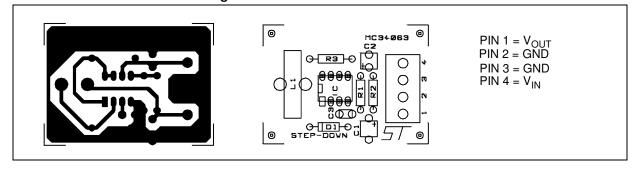


Table 10. Test condition (V_{OUT} = 5 V)

Test	Conditions	Value (typ.)	Unit
Line regulation	$V_{IN} = 15 \text{ to } 25 \text{ V}, I_{O} = 500 \text{ mA}$	5	mV
Load regulation	$V_{IN} = 25 \text{ V}, I_{O} = 50 \text{ to } 500 \text{ mA}$	30	mV
Output ripple	$V_{IN} = 25 \text{ V}, I_{O} = 500 \text{ mA}$	100	mV
Efficiency	$V_{IN} = 25 \text{ V}, I_{O} = 500 \text{ mA}$	80	%
I _{SC}	V_{IN} = 25 V, R_{LOAD} = 0.1 Ω	1.2	Α

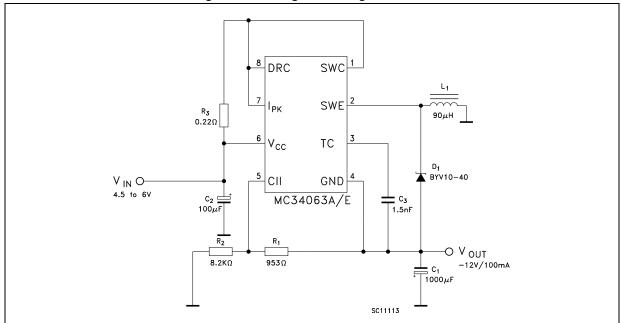


Figure 17. Voltage inverting converter

Figure 18. Printed evaluation board

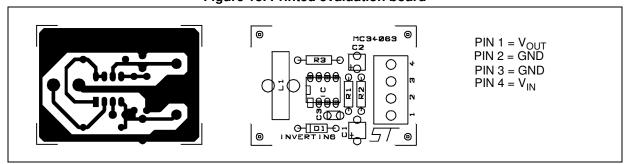


Table 11. Test condition (V_{OUT} = 12 V)

Test	Conditions	Value (typ.)	Unit
Line regulation	$V_{IN} = 4.5 \text{ to } 6 \text{ V}, I_{O} = 100 \text{ mA}$	15	mV
Load regulation	V _{IN} = 5 V, I _O = 10 to 100 mA	20	mV
Output ripple	V _{IN} = 5 V, I _O = 100 mA	230	mV
Efficiency	V _{IN} = 5 V, I _O = 100 mA	58	%
I _{SC}	$V_{IN} = 5 \text{ V}, R_{LOAD} = 0.1 \Omega$	0.9	Α

Table 12. Calculation

Parameter	Step-Up (Discontinuous mode)	Step-Down (Continuous mode)	Voltage Inverting (Discontinuous mode)
t _{on} /t _{off}	$\frac{V_{OUT} + V_F - V_{IN(min)}}{V_{IN(min)} - V_{sat}}$	$\frac{V_{OUT} + V_F}{V_{IN(min)} - V_{sat} - V_{OUT}}$	$\frac{ V_{OUT} + V_F}{V_{IN} - V_{sat}}$
(t _{on} + t _{off}) max	1/f _{min}	1/f _{min}	1/f _{min}
C _T	4.5x10 ⁻⁵ t _{on}	4.5x10 ⁻⁵ t _{on}	4.5x10 ⁻⁵ t _{on}
I _{PK(switch)}	$2I_{out(max)}[(t_{on}/t_{off})+1]$	2I _{out(max)}	$2I_{out(max)}[(t_{on}/t_{off})+1]$
R _{SC}	0.3/I _{PK(switch)}	0.3/I _{PK(switch)}	0.3/I _{PK(switch)}
Co	$\frac{I_{out}t_{on}}{V_{ripple(p-p)}}$	$\frac{I_{PK(switch)}(t_{on} + t_{off})}{8V_{ripple(p-p)}}$	$\frac{I_{out}t_{on}}{V_{ripple(p-p)}}$
L _(min)	$\frac{V_{IN(min)} - V_{sat}}{I_{PK(switch)}} \times t_{on(min)}$	$\frac{I_{IN(min)} - V_{sat} - V_{out}}{I_{PK(switch)}} \times t_{on(min)}$	$\frac{V_{IN(min)} - V_{sat}}{I_{PK(switch)}} \times t_{on(min)}$

Note: $V_{SAT} = Saturation \ voltage \ of \ the \ output \ switch$

 V_F = Forward voltage drop of the output rectifier

The following power supply characteristics must be chosen:

 V_{IN} = Nominal input voltage

 V_{OUT} = Desired output voltage, $|V_{OUT}|$ = 1.25 (1 + R_2/R_1)

I_{OUT} = Desired output current

 f_{MIN} = Minimum desired output switching frequency at the selected values of V_{IN} and I_{O}

 V_{RIPPLE} = Desired peak to peak output ripple voltage. In practice, the calculated capacitor value will and to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.



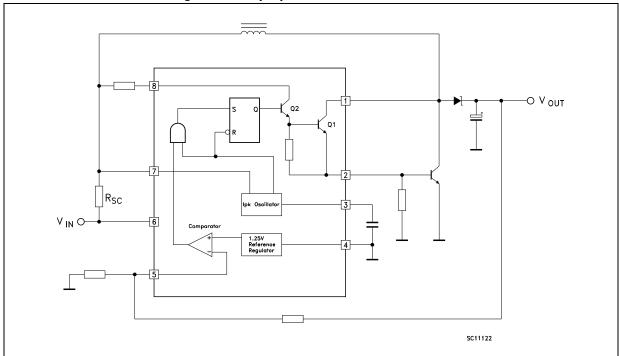
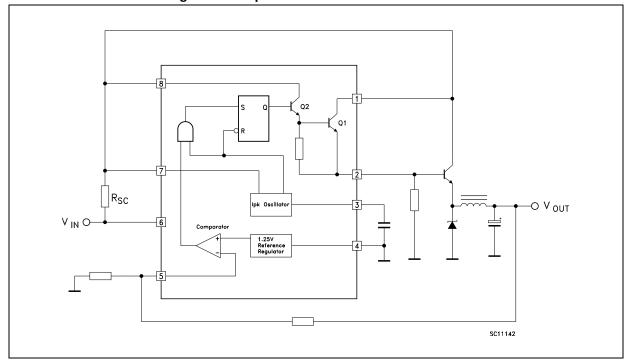


Figure 19. Step-up with external NPN switch





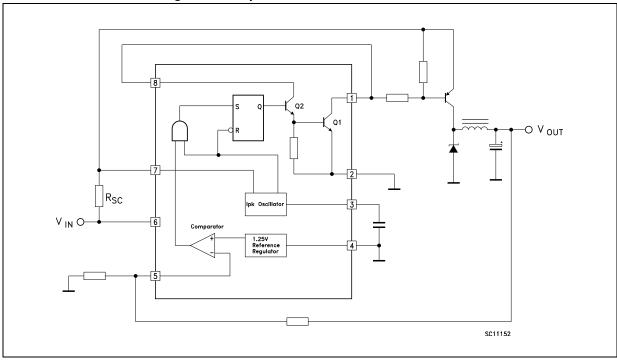
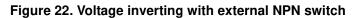
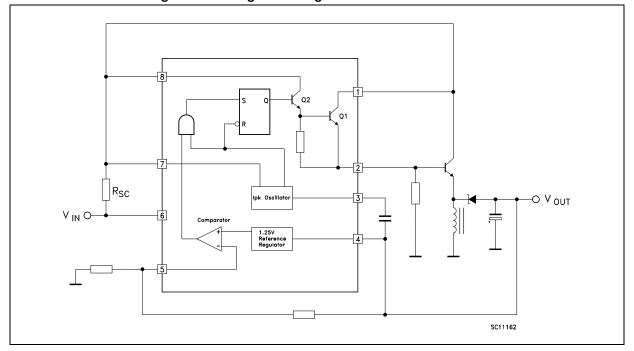


Figure 21. Step-down with external PNP switch





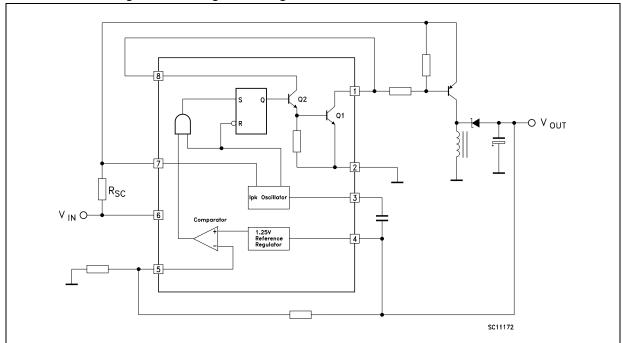
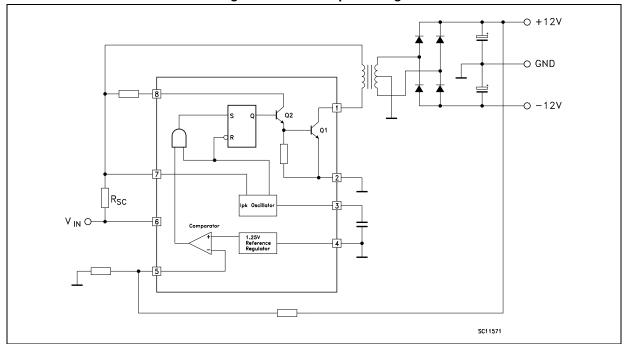


Figure 23. Voltage inverting with external PNP saturated switch





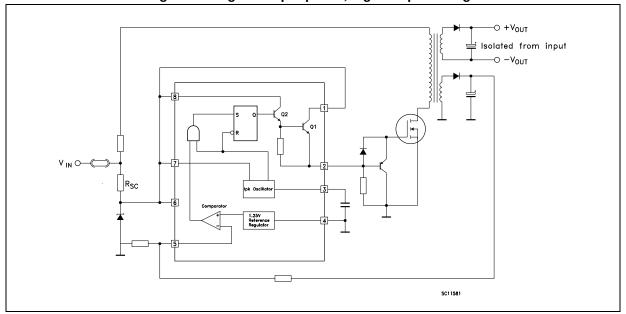


Figure 25. Higher output power, higher input voltage

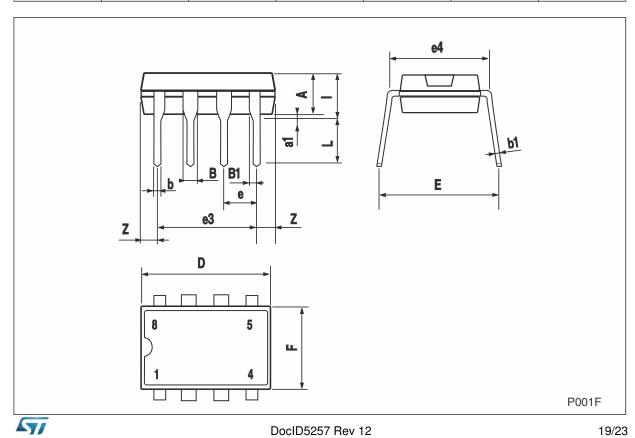


7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

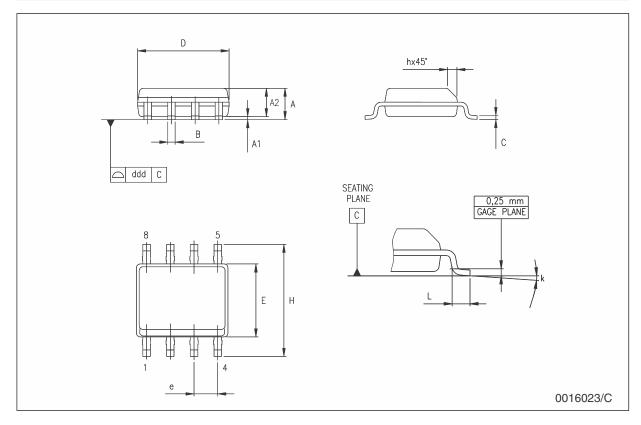
Plastic DIP-8 mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А		3.3			0.130	
a1	0.7			0.028		
В	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
Е		8.8			0.346	
е		2.54			0.100	
еЗ		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
I			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



SO-8 mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04

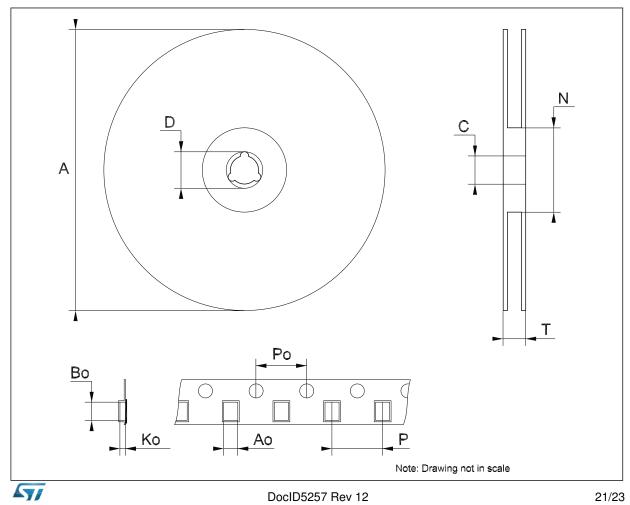


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Tape	&	reel	SO-8	mechanical	data
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Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



8 Revision history

Table 13. Document revision history

Date	Revision	Changes
20-Nov-2007	10	Added Table 1.
24-Apr-2013	11	Removed note in Table 1.
11-Feb-2020	12	Corrected a typo on Reg _{line} parameter (from 5 mV Max. to 10 mV Max.) in <i>Table 7: Comparator</i> .

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